DECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATION DOCKET NO. TS02-622

As a below named inventor, I hereby declare that:

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My residence, post office address and citizenship are as stated below next to my name;

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled Endurance Improvement By Sidewall Nitridation Of Poly PhotogGate For Nonvolatile Memory Devices Using Substrate Or Drain-Side Erase Scheme

the specification of which (check one)			
X is attached hereto.			
was filed on			
Application Serial No.			
and was amended on			-
I hereby state that I have reviewed and a amended by any amendment referred to	pplicable) understand the contents of above.	the above Identified specification including	the clauns, as
I acknowledge the duty to disclose infor 37, Code of Federal Regulations, §1.56	mation which is material to 2).	the examination of this application in acco	rdance with Title
I hereby claim foreign priority benefits u inventor's certificate listed below and ha a filing date before that of the application Prior Foreign Application(s)	nder Title 35. United State ve also identified below an n on which priority is claim	s Code §119 of any foreign application(s) f y foreign application for patent or inventor led:	or patem or s certificate havin
		Priority Clai	med:
(Number)	(Country)	(Day/Month/Year Filed)	
(Number)	(Country)	(Day/Month/Year Filed)	
national or PCT international filing date of (Application Serial No.)		of any United States application(s) listed be disclosed in the prior United States application 2. I acknowledge the duty to disclose mate curred between the filing date of the prior a	pplication and the
Thombs deal		stus) (patented, pending, abandoned) ge are true and that all statements made on made with the knowledge that willful false, der Section 1001 of Title 18 of the United to oplication or any patent issued thereon.	information and statements and States Code and
POWER OF ATTORNEY: As a named in application and transact all business in the GEORGE 0. SAILE. (Reg. No. 1	ventor, I hereby appoint the Patent and Trademark Off	e following attorney(s) and/or agent(s) to p	prosecute this ration no.)
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